# FG/CTL amplifier BA6305/BA6305F

The BA6305 and BA6305F are fast-response wave-shaping preamplifiers for use in VCR CTL amplifiers. They meet the fast REC mode to PB mode response required in VCR CTL amplifiers. The ICs contain a fast-response preamplifier (with precharge function) and a noise-rejecting hysteresis amplifier that converts the CTL signal to a rectangular-wave output. The hysteresis width can be switched between two levels to maintain the S/N ratio, and provide compatibility with various tape speeds.

### Applications

VCR CTL amplifiers
VCR FG amplifiers
VCR DTP amplifiers
Other preamplifier and hysteresis amplifier applications

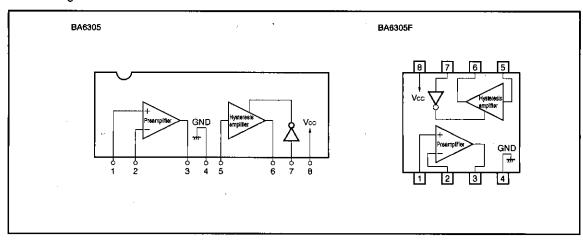
#### Features

- Fast response from strong input when recording to CTL signal playback when playing.
- 2) High gain.
- 3)Schmitt trigger circuit ensures high S/N ratio, and

accurate hysteresis width and level.

- 4)The hysteresis comparator level can be switched to suit the CTL amplifier level.
- 5)Compact SIP 8 pin and SOP 8pin packages.

#### Block diagram



ROHM

# ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Power supply voltage	Vcc	15	V	
Power dissipation	Pd	400 °	mW	
Operating temperature.	Topr	<b>−20~70</b>	°C	
Storage temperature	Tstg	<b>−55∼125</b>	°C	

<sup>\*</sup> Reduced by 4.0mW for each increase in Ta of 1°C over 25°C.

## ●Electrical characteristics (Unless otherwise specified Ta=25°C and Vcc=9V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Operating voltage	Vcc	4.5	_	13.0	V	_
Quiescent current	la	0.6	1.5	2.6	mA	_
Preamplifier bias voltage	V <sub>B pre</sub>	1.0	1.3	1.6	V	
Small-signal preamplifier input resistance	Rins	20	30	40	kΩ	VIN=1.0V
Large-signal preamplifier input resistance	Ren	2.1	4.4	9.0	kΩ	VIN=5.0V
Preamplifier bias input current	lB pre	_	30	300	nĄ	_ ·
Preamplifier output level	VO pre	2.0	2.4	_	V <sub>p-p</sub>	_
Preamplifier open-loop voltage gain	Gvo	64.0	72.5	_	dB	RNF=330kΩ
Preamplifier input conversion noise voltage	V <sub>N pre</sub>	_	3.4	12.0	μ Vrme	DIN Audio R <sub>g</sub> =2.2k Ω
Schmitt circuit input bias potential	V <sub>B hys</sub>	1.6	2.0	2.4	V	` –
Schmitt circuit hysteresis width I	Vhys I	±70	±90	±130	mV₀-p	_
Schmitt circuit hysteresis width II	Vhys II	±200	±250	±360	mV₀-p	_
Schmitt circuit output level	Vohys	5.1	6.6	_	V <sub>p-p</sub>	R <sub>L</sub> =20kΩ

The switching time from REC mode to PB mode is 1 sec. (Max.), and the power on start up time is 3 sec. (Max.).

# ●External dimensions (Units: mm)

